

Absolute Maximum Ratings (Note 1)

Items	Min	Max	Unit
VDD, RTN, PGN_MPS, PG to VSS	-0.3	100	V
CLASS to VSS	-0.3	7	V
Junction Temperature	-40	150	°C
Lead Temperature		260	°C
Storage Temperature	-50	150	°C

Recommended Operating Conditions (Note 2)

Items	Min	Max	Unit
Supply Voltage VDD	0	57	V
Output Current IRTN	0	0.4	A
Operating Temperature	-40	85	°C
Operating Junction Temp	-40	125	°C

ESD Ratings

Items	Description	Value	Unit
$V_{(ESD-HBM)}$	Human Body Model (HBM) ANSI/ESDA/JEDEC JS-001-2017 Classification, Class: 2	±2000	V
$V_{(ESD-CDM)}$	Charged Device Mode (CDM) ANSI/ESDA/JEDEC JS-002-2018 Classification, Class: C3	±1000	V
$I_{LATCH-UP}$	JEDEC STANDARD NO.78E APRIL 2016 Temperature Classification, Class: I	±200	mA

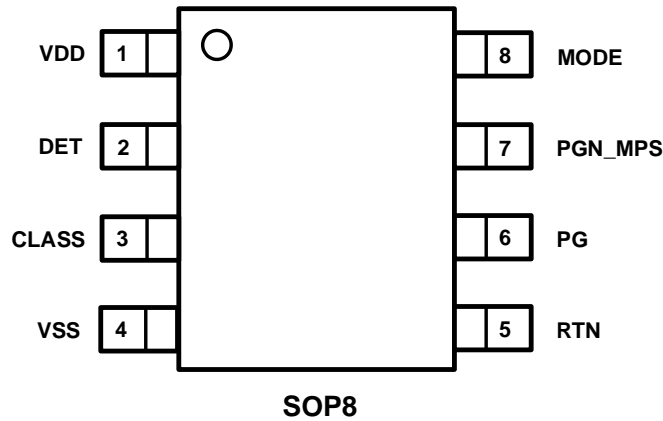
Thermal Resistance

Items	Description	Value	Unit
θ_{JA}	Junction-to-ambient thermal resistance	116.3	°C/W
θ_{JC}	Junction-to-case(top) thermal resistance	53.7	°C/W
ψ_{JC}	Junction-to-case(top) characterization parameter	12.9	°C/W

Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The device is not guaranteed to function outside of its operating conditions.

Package



Top Marking: T7302A/XXXXX (T7302A: Device Code, XXXXX: Inside Code)

Order Information

Part Number	Package	Top Marking	Quantity/ Reel
TMI7302A	SOP8	T7302A XXXXX	3000

TMI7302A devices are Pb-free and RoHS compliant.

Pin Functions

Pin	Name	Function
1	VDD	Positive power input. Connect a bypass capacitor of 68nF between VDD and VSS.
2	DET	Detection Resistor Input. Connect a signature resistor ($R_{DET} = 24.9k\Omega$) from DET to VDD.
3	CLASS	Classification Resistor Input. Connect a resistor (R_{CLS}) from CLS to VSS to set the desired classification current.
4	VSS	Negative Power Supply Terminal.
5	RTN	Isolate the drain of the MOSFET. RTN is connected to the ground of the subsequent DC-DC converter.
6	PG	Open drain output. MODE=0, PG work as MPS switch MODE is floating: PG work as PGOOD indicator, active-high output referenced to RTN.
7	PGN_MPS	Open drain output. MODE=0, PGN_MPS work as PGOOD indicator, active-low output referenced to RTN. MODE=floating: PGN_MPS work as MPS switch.
8	MODE	Internally pulled up to internal 5V. Set The state of this pin determines the function of pin6&pin7. MODE is connected to VSS, PGN_MPS works as PGOOD indicator and PG works as MPS switch; MODE is floating, PG works as PGOOD indicator and PGN_MPS works as MPS switch.

Electrical Characteristics

($V_{DD} = 48V$, all voltages with respect to V_{SS} , $V_{SS} = 0V$; $R_{DET} = 24.9k\Omega$, $R_{CLASS} = 1000\Omega$, $T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted.)

Parameter	Symbol	Conditions	Min	Typ	Max	Units	
Detection							
Detection on	V_{DET_ON}	$V_{VDD}=V_{RTN}=V_{PG}=1.9V$		1.4		V	
Detection off	V_{DET_OFF}	$V_{VDD}=V_{RTN}=V_{PG}=12V$	11	12	13	V	
Detection on/off Hysteresis	V_{DET_H}	Falling below 12V on Threshold		1		V	
DET Leakage Current	V_{DET_LK}	$V_{DET}=V_{VDD}=57V$, Measure I_{DET}		0.1	5	μA	
Detection Current	I_{DET}	$V_{VDD}=V_{RTN}$ $R_{DET}=24.9k\Omega$, Measure $I_{VDD}+I_{RTN}+I_{DET}$	$V_{DD}=1.4V$	55.1	56	56.9	μA
			$V_{DD}=10.1V$	400	408	416	μA
Classification							
V_{CLASS} Output Voltage	V_{CL}	Over a Load Range of 1mA to 30mA		1.22		V	
Classification Current	I_{CLASS0}	$R_{CLASS}=1000\Omega$, $13\leq V_{VDD}\leq 21V$ (guar by V_{CL})	1	1.2	2.8	mA	
	I_{CLASS1}	$R_{CLASS}=115\Omega$, $13\leq V_{VDD}\leq 21V$ (guar by V_{CL})	10.3	10.6	11.3		
	I_{CLASS2}	$R_{CLASS}=66.7\Omega$, $13\leq V_{VDD}\leq 21V$ (guar by V_{CL})	17.7	18.3	19.5		
	I_{CLASS3}	$R_{CLASS}=43\Omega$, $13\leq V_{VDD}\leq 21V$ (guar by V_{CL})	27.1	28.4	29.5		
Classification Lower Threshold	V_{CL_ON}	Regulator Turns on, V_{VDD} Rising	11	12	13	V	
Classification Upper Threshold	V_{CU_OFF}	Regulator Turns off, V_{VDD} Rising	21	22	23	V	
	V_{CU_H}	Hysteresis		0.77		V	
IC Supply Current during Classification	I_{IN_CLASS}	$V_{DD} = 17.5V$, CLASS Floating, RTN Tied to VSS	100	150	200	μA	
Leakage Current	$I_{LEAKAGE}$	$V_{CLASS} = 0V$, $V_{VDD} = 57V$			1	μA	
Pass Device							
On Resistance	$R_{DS(ON)}$	$I_{RTN}=300mA$		0.6		Ω	
Leakage Current	I_{SW_LK}	$V_{VDD}=V_{RTN}=57V$		1	15	μA	
Current Limit	I_{LIMIT}	$V_{RTN}=1V$	400	450	500	mA	
Inrush Limit	I_{INRUSH}	$V_{RTN}=2V$, $R_{ILM}=178k\Omega$	120	150	200	mA	
Fold-back threshold		V_{RTN} Rising	9.5	10	10.5	V	
Fold-back deglitch time		V_{RTN} rising to when current limit changes to inrush current limit		345		μs	
Inrush to Operating Mode Delay	t_{DELAY}	t_{DELAY} = minimum PG current pulse width after entering into power mode	80	94	110	ms	
PGOOD-PG pin							
PG Sink Current		$V_{RTN} = 1.5V$, $V_{PG} = 0.8V$, during inrush period	130	230	330	μA	
PG Off -leakage Current		$V_{PG} = 48V$		0.1	1	μA	

Electrical Characteristics

($V_{DD} = 48V$, all voltages with respect to V_{SS} , $V_{SS} = 0V$; $R_{DET} = 24.9k\Omega$, $R_{CLASS} = 1000\Omega$, $T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted.)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
PGOOD-PGN_MPS pin						
Output Low Voltage		Output Low Voltage $I_{PG} = 400\mu A$		0.18	0.4	V
Leakage Current		$V_{PG} = 57\text{ V}$, $V_{RTN} = 0\text{ V}$		0.1	1	μA
MPS						
Automatic MPS falling current threshold	I_{MPS_TH}	Startup has completed, I_{RTN} falling threshold to generate MPS pulses		35		mA
Hysteresis on RTN current	HYS			3		mA
MPS pulsed mode duty cycle		MPS pulsed current ON time	65	75	85	ms
		MPS pulsed current OFF time	195	225	255	ms
		MPS pulsed current duty cycle	24.7%	25%	25.3%	
UVLO						
Voltage at VDD	V_{ON}	VDD Rising	37.2	38.6	40	V
	V_{OFF}	VDD Falling		31		
Thermal Shutdown						
Thermal Shut down Temperature (Note3)	T_{RISE}	Temperature Rising	140	152	160	$^\circ\text{C}$
Hysteresis	T_{HYS}			20		$^\circ\text{C}$
Bias Current						
Operating Current	$I_{Q(VDD)}$	$V_{DD} = 48V$, Pins 5, 6 Floating Measure I_{VDD}		240	450	μA

Note 3: Guaranteed by design

Block Diagram

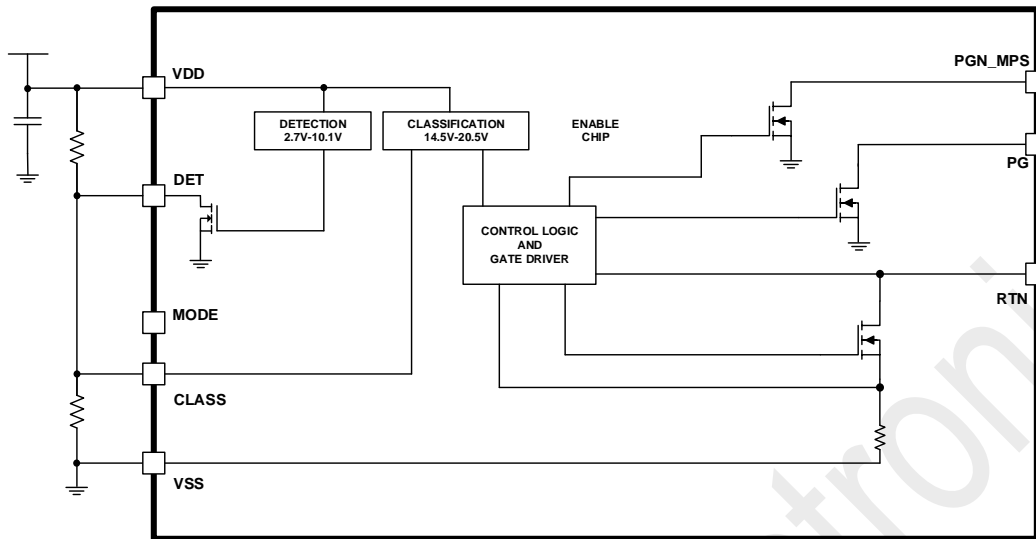


Figure 2 TMI7302A Block Diagram

Operation Description

Overview

The TMI7302A operates in the manner described here and in the IEEE 802.3af Powered Device (PD) specifications. This device (along with the power sourcing element (PSE)) operates as a safety device to supply potentially lethal voltages only when the power sourcing element recognizes a unique, tightly specified resistance at the end of an unknown length of ethernet cable.

Detection Mode ($1.4V \leq VDD \leq 10.1V$)

In detection mode, PSE applies two voltages in the range of 1.4V to 10.1V (minimum step size is 1V) to VIN, and records the current measurement values at these two points. Then, PSE calculates DV/DI to ensure that the 24.9kΩ characteristic resistor is connected. Connect a characteristic resistor (RDET) between VDD and DET to ensure correct feature detection. In detection mode, TMI7302A pulls DET low. When the input voltage exceeds 12.5V, DET becomes high impedance. In detection mode, most of the internal circuits of TMI7302A is in the off state, and the bias current is less than 10μA.

Classification Mode ($12.6V \leq VIN \leq 20V$)

In the classification mode, the PSE classifies the PD according to the power consumption required by the PD, so that the PSE can effectively manage the power allocation. Connect an external resistor (RCLASS) between CLASS and VSS to set the classification current. The PSE determines the PD level by applying a voltage to the PD input and measuring the current output by the PSE. When the voltage applied by the PSE is between 12.6V and 20V, the TMI7302A feeds back the classification current. PSE uses classification current information to classify PD power requirements. The classification current includes the current drawn by RCLS and the power supply current of TMI7302A, so the total current drawn by PD is within the index range of IEEE802.3af standard. When the device is in power mode, the classification current is turned off.

Power Mode

When VIN rises above the undervoltage lockout threshold (V_{ON}), TMI7302A enters the power supply mode. When VIN rises above V_{ON} , TMI7302A turns on the internal n-channel isolation MOSFET, connects VSS to RTN, and the internal inrush current limit is set to 150mA. When the voltage at RTN approaches VSS and the inrush current falls below the inrush threshold, the isolation MOSFET is fully turned on. Once the isolation MOSFET is fully turned on, TMI7302A changes the current limit to 450mA. Before the power MOSFET is fully turned on, the power-good open-drain output remains turned off for a duration of at least t_{DELAY} to prohibit subsequent DC/DC converters during the surge.

Undervoltage Lockout

The working voltage of TMI7302A is as high as 57V, the UVLO threshold (V_{ON}) of the circuit is $\approx 38.6V$; the UVLO threshold (V_{OFF}) of the circuit is 31V. When the input voltage is higher than V_{ON} , TMI7302A enters the power supply mode and the internal MOSFET turns on. When the input voltage is lower than V_{OFF} for more than t_{OFF_DLY} , the MOSFET turns off. The power-good output uses an open-drain output to disable subsequent DC-DC converters before the n-channel isolation MOSFET is fully turned on. Before the internal isolation MOSFET is fully turned on, the PG switch is off, and the hold time is t_{DELAY} . When exiting the thermal shutdown state, the PG switch is also off.

PGOOD Output of PGN_MPS

PGN_MPS is an active low output that is pulled to VSS when the device is in the steady-state power mode. It remains in a high impedance state at all other times.

PGOOD Output of PG

PG is an active high output that is pulled to VSS when the device is in inrush phase. It remains in a high impedance state at all other times.

Maintain Power Signature

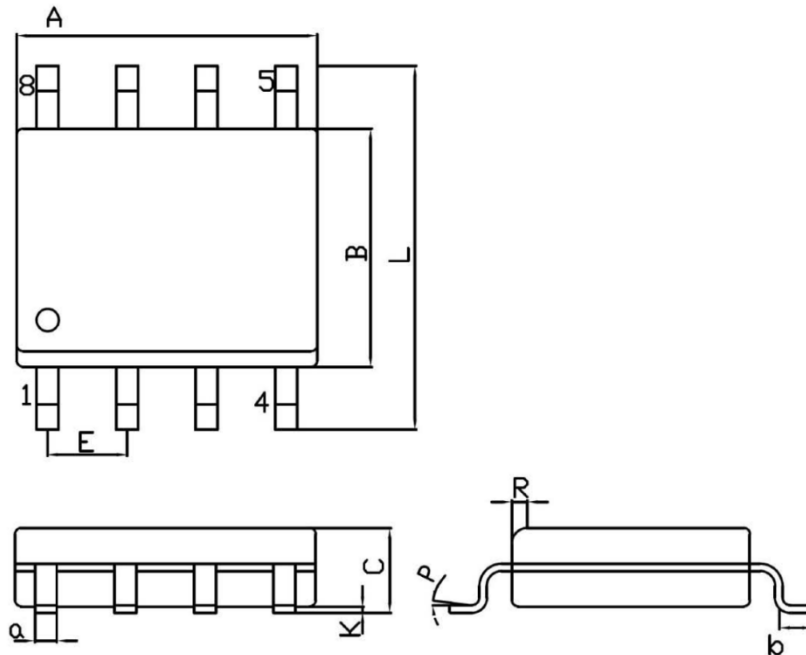
The MPS is an electrical signature presented by the PD to assure the PSE that it is still present after operating voltage is applied. For IEEE802.3af/at PD, a valid MPS consists of a minimum dc current of 10mA, or a 10mA pulsed current for at least 75ms every 325ms, and an AC impedance lower than 26.3k Ω in parallel with 0.05 μF . The TMI7302A has 2 pins can generate MPS pulses. It is selectable through the MODE input pin. If the current through the RTN-to-VSS path is below about 28mA, the TMI7302A automatically generates the MPS pulsed current through the PGN_MPS(PG) output pin, the current amplitude being adjustable with an external resistor.

Thermal Shutdown Protection

TMI7302A has thermal shutdown protection function to avoid overheating. If the junction temperature exceeds the 152°C thermal shutdown threshold, the TMI7302A will turn off the internal power MOSFET. When the junction temperature drops below 132°C, the device enters surge mode and then returns to power mode. Surge mode ensures that the internal power MOSFET turns off the subsequent DC-DC converter before turning on.

Package Information

SOP8



Unit: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
A	4.70	5.10	C	1.35	1.75
B	3.70	4.10	a	0.35	0.49
L	6.00	6.40	R	0.30	0.60
E	1.27 BSC		P	0°	7°
K	0.12	0.22	b	0.40	1.25

Note:

- 1) All dimensions are in millimeters.
- 2) Package length does not include mold flash, protrusion or gate burr.
- 3) Package width does not include inter lead flash or protrusion.
- 4) Lead popularity (bottom of leads after forming) shall be 0.10 millimeters max.
- 5) Pin 1 is lower left pin when reading top mark from left to right.

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